

# TK5A65DA

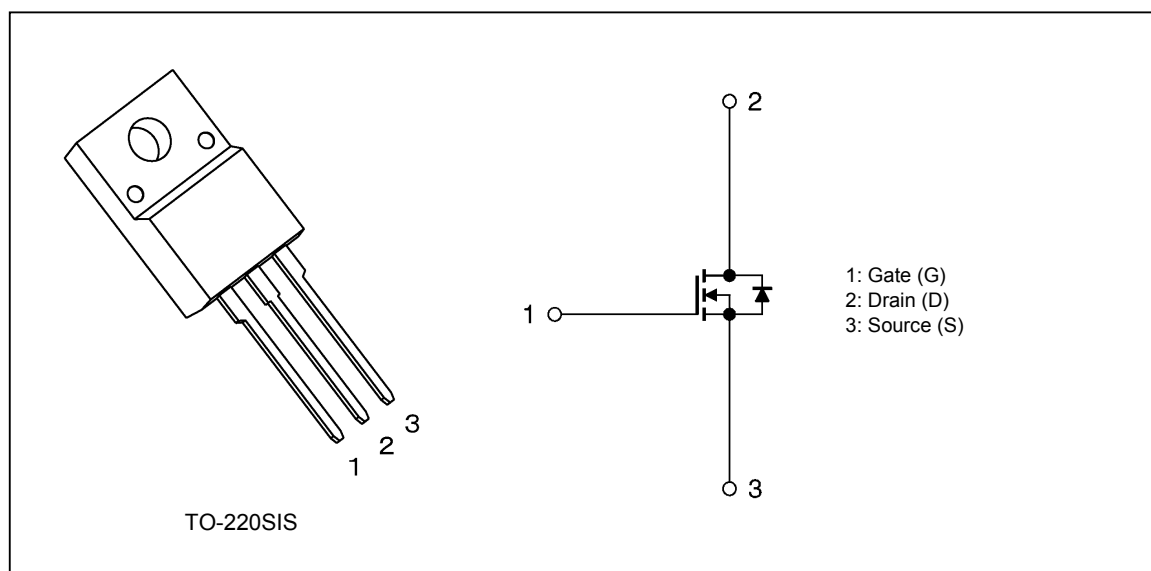
## 1. Applications

- Switching Voltage Regulators

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 1.34 \Omega$  (typ.)
- (2) High forward transfer admittance:  $|Y_{fs}| = 3.1 \text{ S}$  (typ.)
- (3) Low leakage current:  $I_{DSS} = 10 \mu\text{A}$  (max) ( $V_{DS} = 650 \text{ V}$ )
- (4) Enhancement mode:  $V_{th} = 2.4$  to  $4.4 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics               | Symbol    | Rating     | Unit             |
|-------------------------------|-----------|------------|------------------|
| Drain-source voltage          | $V_{DSS}$ | 650        | V                |
| Gate-source voltage           | $V_{GSS}$ | $\pm 30$   |                  |
| Drain current (DC)            | $I_D$     | 4.5        | A                |
| Drain current (pulsed)        | $I_{DP}$  | 18         |                  |
| Power dissipation             | $P_D$     | 35         | W                |
| Single-pulse avalanche energy | $E_{AS}$  | 194        | mJ               |
| Avalanche current             | $I_{AR}$  | 4.5        | A                |
| Repetitive avalanche energy   | $E_{AR}$  | 3.5        | mJ               |
| Channel temperature           | $T_{ch}$  | 150        | $^\circ\text{C}$ |
| Storage temperature           | $T_{stg}$ | -55 to 150 |                  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

## 5. Thermal Characteristics

| Characteristics                       | Symbol         | Max  | Unit |
|---------------------------------------|----------------|------|------|
| Channel-to-case thermal resistance    | $R_{th(ch-c)}$ | 3.57 | °C/W |
| Channel-to-ambient thermal resistance | $R_{th(ch-a)}$ | 62.5 |      |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 90\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 16.9\text{ mH}$ ,  $R_G = 25\ \Omega$ ,  $I_{AR} = 4.5\text{ A}$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

## 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics                | Symbol        | Test Condition                                     | Min | Typ. | Max     | Unit          |
|--------------------------------|---------------|----------------------------------------------------|-----|------|---------|---------------|
| Gate leakage current           | $I_{GSS}$     | $V_{GS} = \pm 30\text{ V}$ , $V_{DS} = 0\text{ V}$ | —   | —    | $\pm 1$ | $\mu\text{A}$ |
| Drain cut-off current          | $I_{DSS}$     | $V_{DS} = 650\text{ V}$ , $V_{GS} = 0\text{ V}$    | —   | —    | 10      |               |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}$ , $V_{GS} = 0\text{ V}$       | 650 | —    | —       | V             |
| Gate threshold voltage         | $V_{th}$      | $V_{DS} = 10\text{ V}$ , $I_D = 1\text{ mA}$       | 2.4 | —    | 4.4     |               |
| Drain-source on-resistance     | $R_{DS(ON)}$  | $V_{GS} = 10\text{ V}$ , $I_D = 2.3\text{ A}$      | —   | 1.34 | 1.67    | $\Omega$      |
| Forward transfer admittance    | $ Y_{fs} $    | $V_{DS} = 10\text{ V}$ , $I_D = 2.3\text{ A}$      | 0.8 | 3.1  | —       | S             |

### 6.2. Dynamic Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics                | Symbol    | Test Condition                                                      | Min | Typ. | Max | Unit          |
|--------------------------------|-----------|---------------------------------------------------------------------|-----|------|-----|---------------|
| Input capacitance              | $C_{iss}$ | $V_{DS} = 25\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$ | —   | 700  | —   | $\mu\text{F}$ |
| Reverse transfer capacitance   | $C_{rss}$ |                                                                     | —   | 4    | —   |               |
| Output capacitance             | $C_{oss}$ |                                                                     | —   | 70   | —   |               |
| Switching time (rise time)     | $t_r$     | See Figure 6.2.1.                                                   | —   | 20   | —   | $\mu\text{s}$ |
| Switching time (turn-on time)  | $t_{on}$  |                                                                     | —   | 40   | —   |               |
| Switching time (fall time)     | $t_f$     |                                                                     | —   | 9    | —   |               |
| Switching time (turn-off time) | $t_{off}$ |                                                                     | —   | 60   | —   |               |

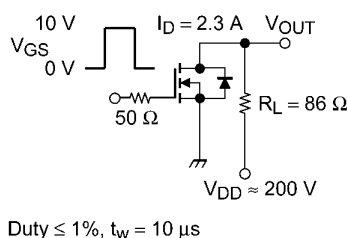


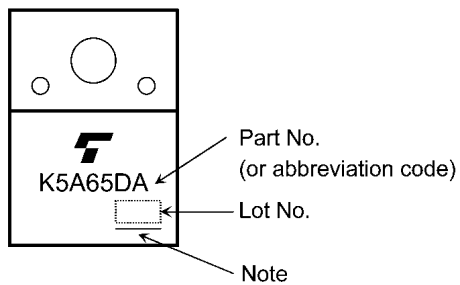
Fig. 6.2.1 Switching Time Test Circuit

### 6.3. Gate Charge Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics                                 | Symbol   | Test Condition                                                                | Min | Typ. | Max | Unit |
|-------------------------------------------------|----------|-------------------------------------------------------------------------------|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | $Q_g$    | $V_{DD} \approx 400\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 4.5\text{ A}$ | —   | 16   | —   | nC   |
| Gate-source charge                              | $Q_{gs}$ |                                                                               | —   | 11   | —   |      |
| Gate-drain charge                               | $Q_{gd}$ |                                                                               | —   | 5    | —   |      |

### 6.4. Source-Drain Characteristics ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

| Characteristics                         | Symbol    | Test Condition                                                                              | Min | Typ. | Max  | Unit          |
|-----------------------------------------|-----------|---------------------------------------------------------------------------------------------|-----|------|------|---------------|
| Reverse drain current (DC) (Note 1)     | $I_{DR}$  | —                                                                                           | —   | —    | 4.5  | A             |
| Reverse drain current (pulsed) (Note 1) | $I_{DRP}$ | —                                                                                           | —   | —    | 18   |               |
| Diode forward voltage                   | $V_{DSF}$ | $I_{DR} = 4.5\text{ A}$ , $V_{GS} = 0\text{ V}$                                             | —   | —    | -1.7 | V             |
| Reverse recovery time                   | $t_{rr}$  | $I_{DR} = 4.5\text{ A}$ , $V_{GS} = 0\text{ V}$<br>$-dI_{DR}/dt = 100\text{ A}/\mu\text{s}$ | —   | 1100 | —    | ns            |
| Reverse recovery charge                 | $Q_{rr}$  |                                                                                             | —   | 7.7  | —    | $\mu\text{C}$ |

**7. Marking (Note)****Fig. 7.1 Marking**

Note: A line under a Lot No. identifies the indication of product Labels.

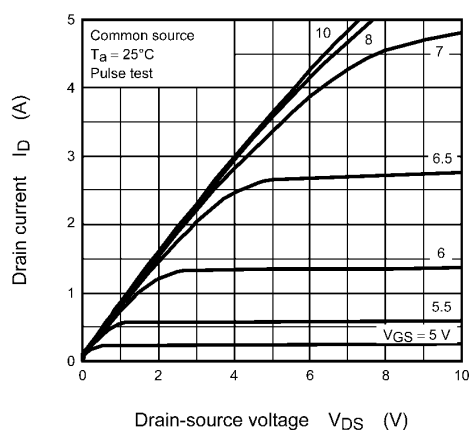
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

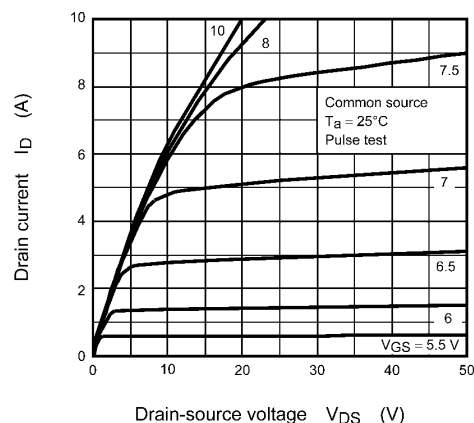
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

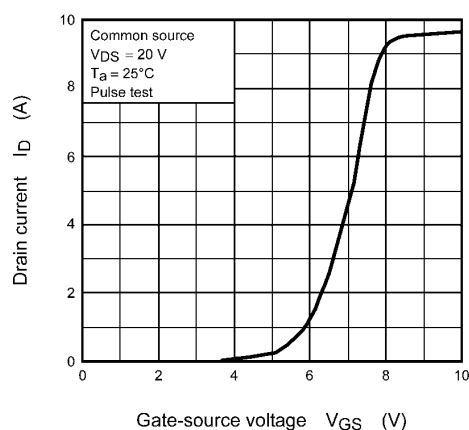
# 8. Characteristics Curves (Note)



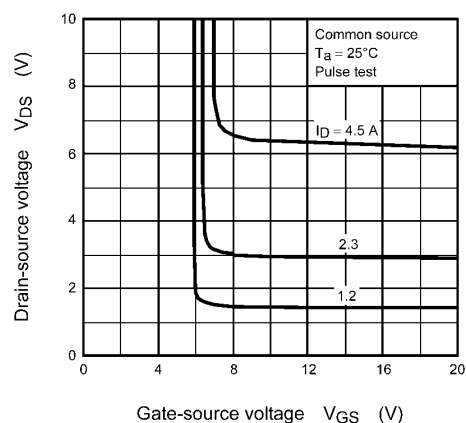
**Fig. 8.1**  $I_D - V_{DS}$



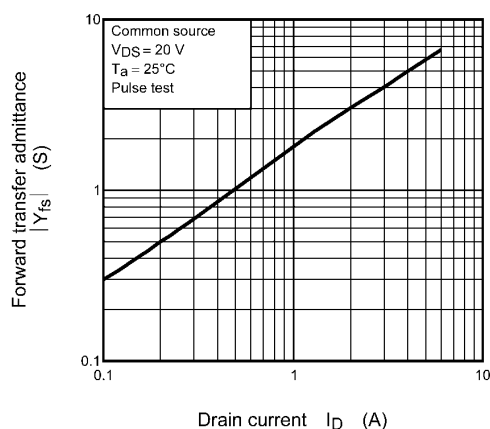
**Fig. 8.2**  $I_D - V_{DS}$



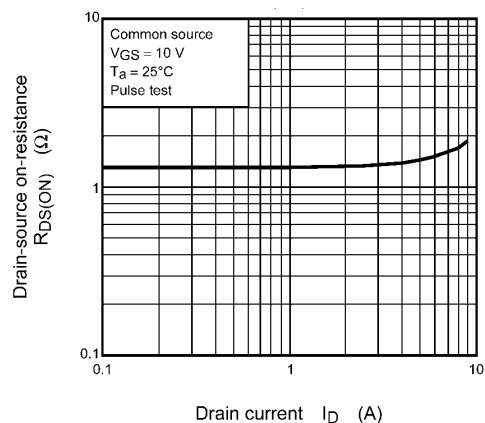
**Fig. 8.3**  $I_D - V_{GS}$



**Fig. 8.4**  $V_{DS} - V_{GS}$



**Fig. 8.5**  $|Y_{fs}| - I_D$



**Fig. 8.6**  $R_{DS(ON)} - I_D$

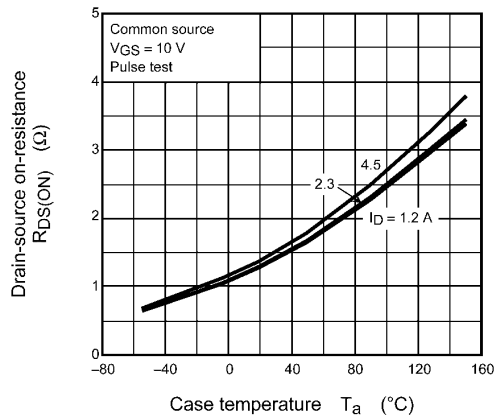
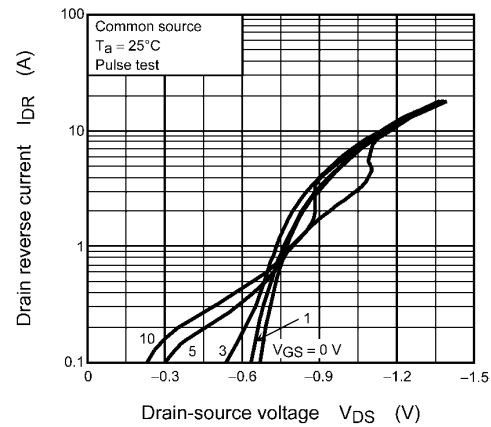
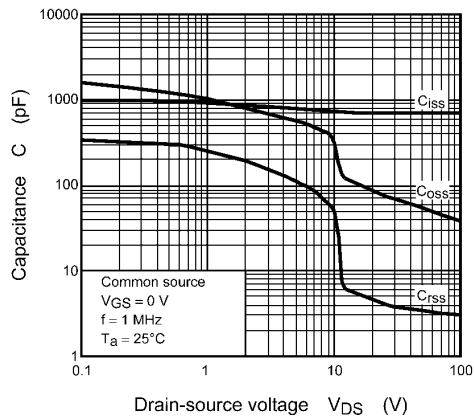
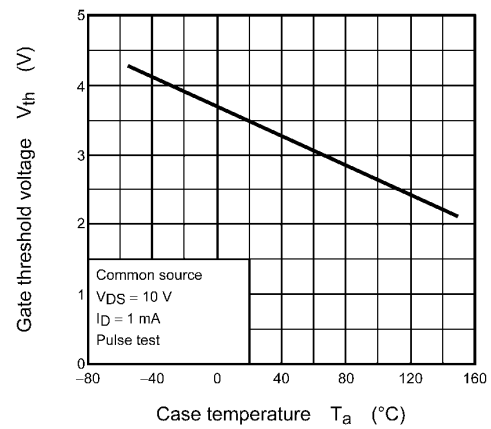
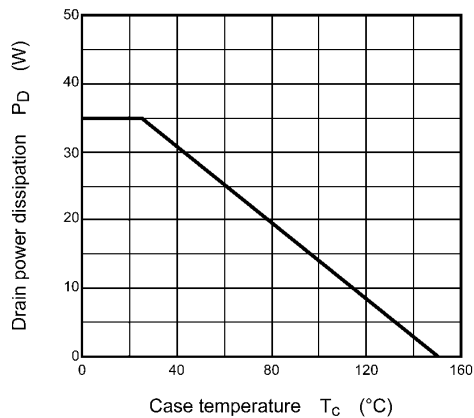
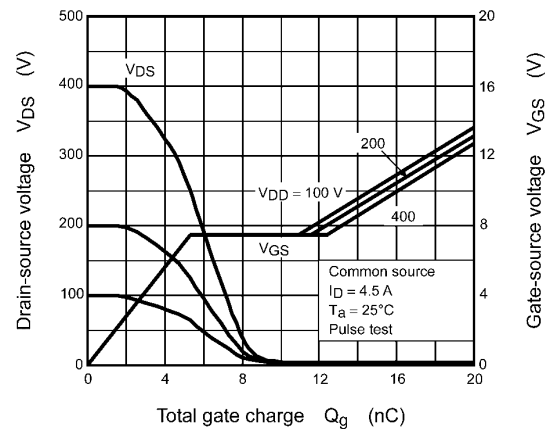
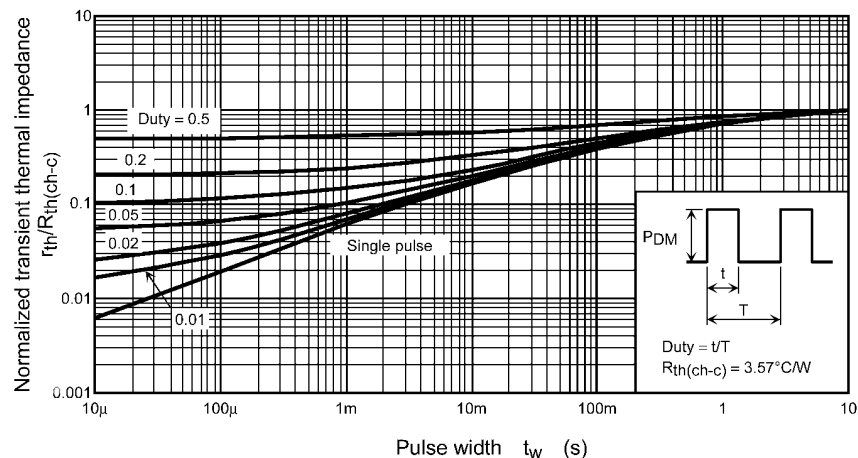
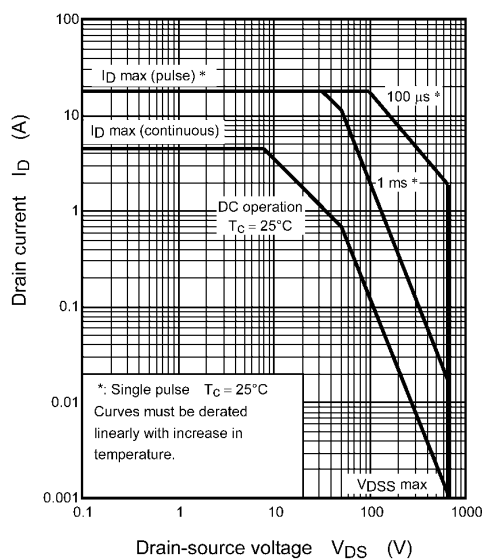
Fig. 8.7  $R_{DS(ON)} - T_a$ Fig. 8.8  $I_{DR} - V_{DS}$ Fig. 8.9  $C - V_{DS}$ Fig. 8.10  $V_{th} - T_a$ Fig. 8.11  $P_D - T_c$   
(Guaranteed Maximum)

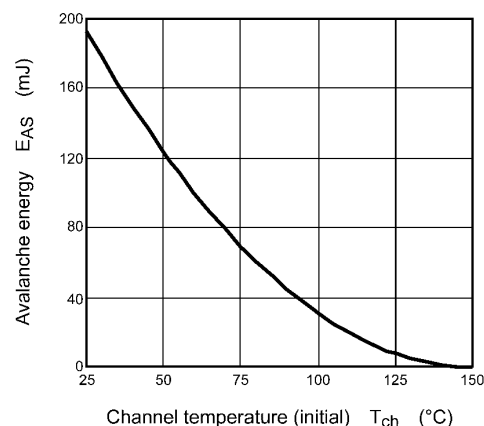
Fig. 8.12 Dynamic Input/Output Characteristics



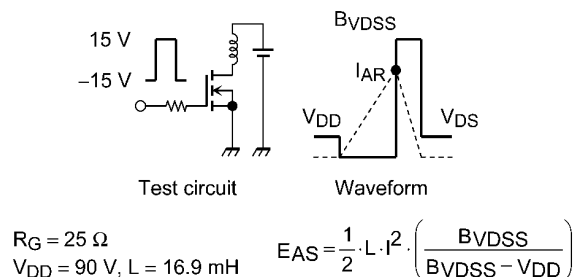
**Fig. 8.13**  $r_{th}/R_{th(ch-c)} - t_w$   
(Guaranteed Maximum)



**Fig. 8.14** Safe Operating Area  
(Guaranteed Maximum)



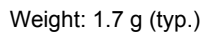
**Fig. 8.15**  $E_{AS} - T_{ch}$   
(Guaranteed Maximum)



**Fig. 8.16** Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Unit: mm



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Rev.2.0

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